

2SC5121

Silicon NPN triple diffusion planar type

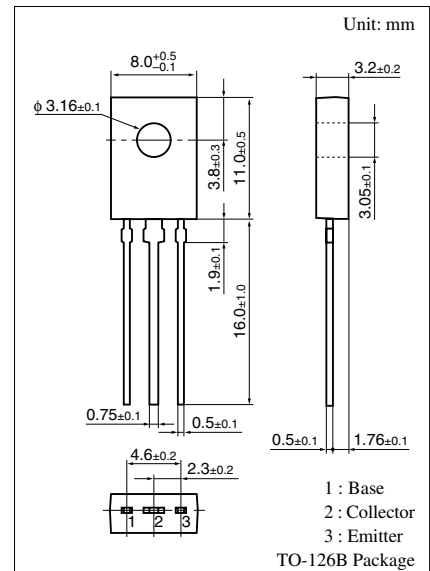
For general amplification

■ Features

- High collector to base voltage V_{CBO}
- High collector to emitter voltage V_{CEO}
- Small collector output capacitance C_{ob}
- TO-126B package, which is fitted to a heat sink without any insulation parts

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

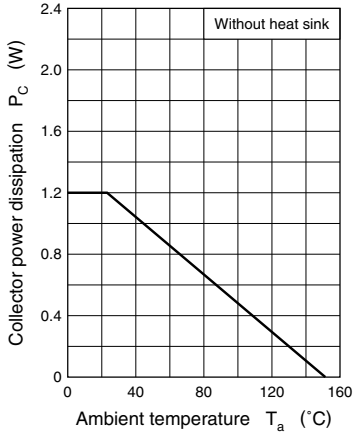
| Parameter | Symbol | Rating | Unit |
|------------------------------|-----------|-------------|------------------|
| Collector to base voltage | V_{CBO} | 400 | V |
| Collector to emitter voltage | V_{CEO} | 400 | V |
| Emitter to base voltage | V_{EBO} | 7 | V |
| Peak collector current | I_{CP} | 100 | mA |
| Collector current | I_C | 70 | mA |
| Collector power dissipation | P_C | 1.2 | W |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |



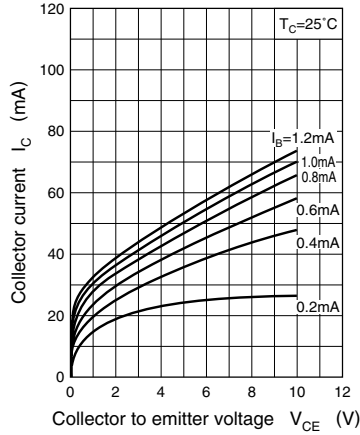
■ Electrical Characteristics $T_C = 25^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|---------------|---|-----|-----|-----|---------------|
| Collector cutoff current | I_{CBO} | $V_{CB} = 300\text{ V}, I_E = 0$ | | | 10 | μA |
| | Hot I_{CEO} | $V_{CE} = 380\text{ V}, I_B = 0, T_a = 80^\circ\text{C}$ | | | 10 | μA |
| Collector to emitter voltage | V_{CEO} | $I_C = 100\ \mu\text{A}, I_B = 0$ | 400 | | | V |
| Emitter to base voltage | V_{EBO} | $I_E = 1\ \mu\text{A}, I_C = 0$ | 7 | | | V |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10\text{ V}, I_C = 5\text{ mA}$ | 30 | | 150 | |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 50\text{ mA}, I_B = 5\text{ mA}$ | | | 1.2 | V |
| Transition frequency | f_T | $V_{CB} = 10\text{ V}, I_E = -10\text{ mA}, f = 200\text{ MHz}$ | 50 | 80 | | MHz |
| Collector output capacitance | C_{ob} | $V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$ | | 4 | 8 | pF |

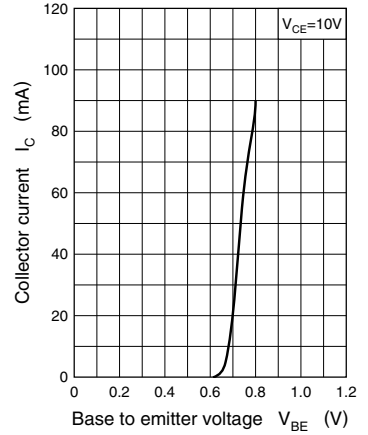
$P_C - T_a$



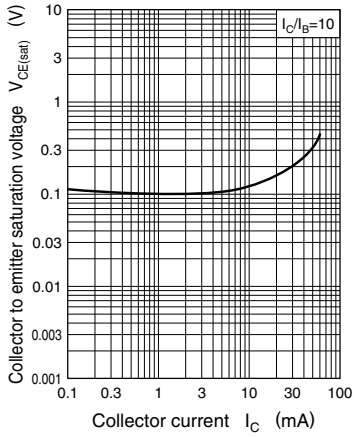
$I_C - V_{CE}$



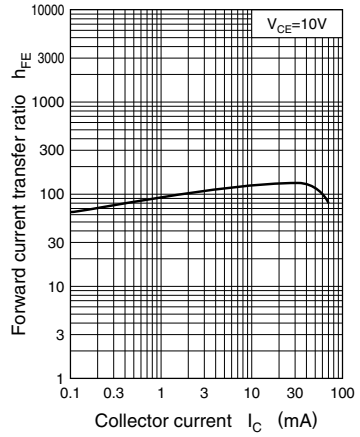
$I_C - V_{BE}$



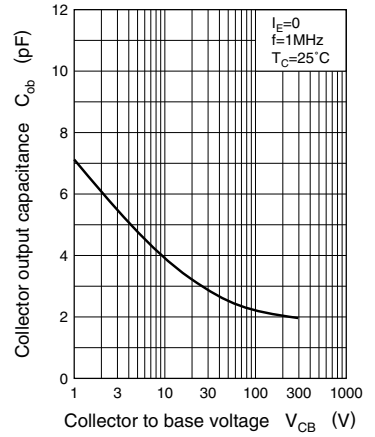
$V_{CE(sat)} - I_C$



$h_{FE} - I_C$



$C_{ob} - V_{CB}$



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